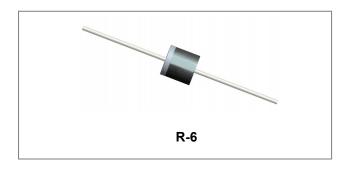


#### Technical Data Data Sheet N1520, Rev. A





## 20SQ200 SCHOTTKY BARRIER RECTIFIER



### **Features**

- Super-high speed & low noise switching
- Low voltage drop
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



## **Mechanical Data**

- DC-DC converters
- AC adapter
- · High frequency rectification circuit
- · Bypass diodes

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	200	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>c</sub> = 135°C, rectangular wave form	20	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse, T <sub>C</sub> = 25 °C	300	А

### **Electrical Characteristics:**

Characteristics	Symbol	Condition		Тур.	Max.	Units
Peak Forward Voltage*	V <sub>FM1</sub>	I <sub>FM</sub> =20.0A,Ta=25℃		-	1.10	V
	V <sub>FM2</sub>	I <sub>FM</sub> =20.0A,Ta=125℃		-	1.00	V
Peak Reverse Current*	I <sub>RRM1</sub>	\/ <b>-</b> \/	Ta=25℃	-	1	mA
	I <sub>RRM2</sub>	$V_{RM}=V_{RRM}$	Ta=125℃	-	8	
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25  ^{\circ}C, f_{SIG} = 1MHz$		-	400	pF

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%



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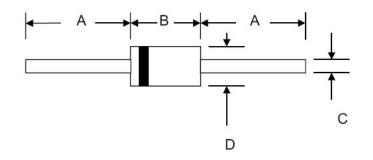




## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Thermal Resistance, Junction to lead	R <sub>θJ-L</sub>	-	8	°C/W
Approximate Weight	wt	-	2.24	g
Case Style	R-6			

#### **Mechanical Dimensions R-6**



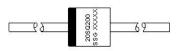
CVMDOL	Millin	neters	Inches		
SYMBOL	Min.	Max.	Min.	Max.	
А	25.4	-	1.000	-	
В	8.60	9.10	0.340	0.360	
С	1.2	1.3	0.048	0.052	
D	8.60	9.10	0.340	0.360	

## **Ordering Information**

Device	Package	Shipping	
20SQ200	R-6(Pb-Free)	500pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Marking Diagram**

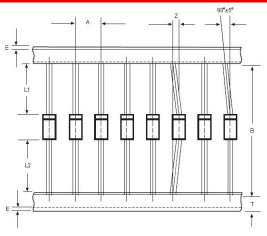


Where XXXXX is YYWWL

20 = Forward Current (20A)
S = Package Type
Q = Device Type
200 = Reverse Voltage (200V)
SSG = SSG

YY = Year
WW = Week
L = Lot Number

# **Carrier Tape Specification R-6**



SYMBOL	Millimeters		
	Min.	Max.	
Α	9.50	10.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
E	-	0.80	
IL1-L2I	-	1.0	

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